

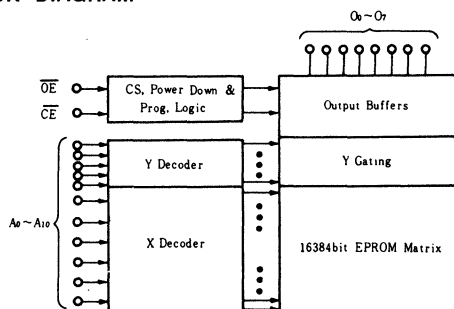
HN462716, HN462716G

2048-word × 8-bit U.V. Erasable and Electrically Programmable Read Only Memory

The HN462716 is a 2048 word by 8 bit erasable and electrically programmable ROMs. This device is packaged in a 24-pin, dual-in-line package with transparent lid. The transparent lid allows the user to expose the chip to ultraviolet light to erase the bit pattern, whereby a new pattern can then be written into the device.

- Single Power Supply +5V ±5%
- Simple Programming Program Voltage: +25V DC
Programs with One 50ms Pulse
- Static No Clocks Required
- Inputs and Outputs TTL Compatible During Both Read and Program Modes
- Fully Decoded-on Chip Address Decode
- Access Time 450ns Max.
- Low Power Dissipation . . 555mW Max. Active Power
161mW Max. Standby Power
- Three State Output OR- Tie Capability
- Interchangeable with Intel 2716

■ BLOCK DIAGRAM



■ PROGRAMMING OPERATION

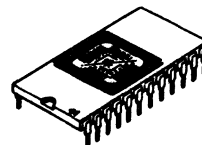
Mode	Pins	\overline{CE} (18)	\overline{OE} (20)	V_{PP} (21)	V_{CC} (24)	Outputs (9~11, 13~17)
Read		V_{IL}	V_{IL}	+5	+5	Dout
Deselect		Don't Care	V_{IH}	+5	+5	High Z
Power Down		V_{IH}	Don't Care	+5	+5	High Z
Program		Pulsed V_{IL} to V_{IH}	V_{IH}	+25	+5	Din
Program Verify		V_{IL}	V_{IL}	+25	+5	Dout
Program Inhibit		V_{IL}	V_{IH}	+25	+5	High Z

■ ABSOLUTE MAXIMUM RATINGS

Item	Symbol	Value	Unit
Operating Temperature Range	T_{op}	0 to +70	°C
Storage Temperature Range	T_{stg}	-65 to +125	°C
All Input and Output Voltages*	V_T	-0.3 to +7	V
V_{PP} Supply Voltage*	V_{PP}	-0.3 to +28	V

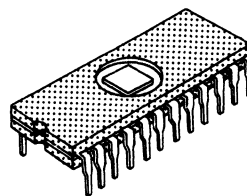
* With respect to Ground

HN462716



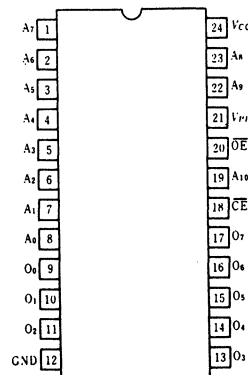
(DC-24C)

HN462716G



(DG-24B)

■ PIN ARRANGEMENT



(Top View)

■ READ OPERATION

● DC AND OPERATING CHARACTERISTICS ($T_a=0$ to $+70^\circ\text{C}$, $V_{CC}=5\text{V}\pm 5\%$, $V_{PP}=V_{CC}\pm 0.6\text{V}$)

Item	Symbol	Test Condition	min.	typ.	max.	Unit
Input Leakage Current	I_{LI}	$V_{IN}=5.25\text{V}$	—	—	10	μA
Output Leakage Current	I_{LO}	$V_{OUT}=5.25\text{V}/0.4\text{V}$	—	—	10	μA
V_{PP} Current	I_{PP1}	$V_{PP}=5.85\text{V}$	—	—	5	mA
V_{CC} Current (Standby)	I_{CC1}	$\overline{\text{CE}}=V_{IH}$, $\overline{\text{OE}}=V_{IL}$	—	13	25	mA
V_{CC} Current (Active)	I_{CC2}	$\overline{\text{OE}}=\overline{\text{CE}}=V_{IL}$	—	56	100	mA
Input Low Voltage	V_{IL}		-0.1	—	0.8	V
Input High Voltage	V_{IH}		2.0	—	$V_{CC}+1$	V
Output Low Voltage	V_{OL}	$I_{OL}=2.1\text{mA}$	—	—	0.4	V
Output High Voltage	V_{OH}	$I_{OH}=-400\mu\text{A}$	2.4	—	—	V

Note : V_{IL} must be applied simultaneously or before V_{PP} and removed simultaneously or after V_{PP} .

● AC CHARACTERISTICS ($T_a=0$ to $+70^\circ\text{C}$, $V_{CC}=5\text{V}\pm 5\%$, $V_{PP}=V_{CC}\pm 0.6\text{V}$)

Parameter	Symbol	Test Condition	min.	typ.	max.	Unit
Address to Output Delay	t_{ACC}	$\overline{\text{OE}}=\overline{\text{CE}}=V_{IL}$	—	—	450	ns
$\overline{\text{CE}}$ to Output Delay	t_{CE}	$\overline{\text{OE}}=V_{IL}$	—	—	450	ns
$\overline{\text{OE}}$ to Output Delay	t_{OE}	$\overline{\text{CE}}=V_{IL}$	—	—	120	ns
$\overline{\text{OE}}$ High to Output Float *	t_{DF}	$\overline{\text{CE}}=V_{IL}$	0	—	100	ns
Address to Output Hold	t_{OH}	$\overline{\text{OE}}=\overline{\text{CE}}=V_{IL}$	0	—	—	ns

* : t_{DF} defines the time at which the output achieves the open circuit condition and is not referenced to output voltage levels.

● CAPACITANCE ($T_a=25^\circ\text{C}$, $f=1\text{MHz}$)

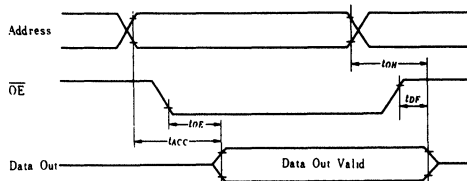
Item	Symbol	Test Condition	typ.	max.	Unit
Input Capacitance	C_{in}	$V_{IN}=0\text{V}$	—	6	pF
Output Capacitance	C_{out}	$V_{OUT}=0\text{V}$	—	12	pF

● SWITCHING CHARACTERISTICS

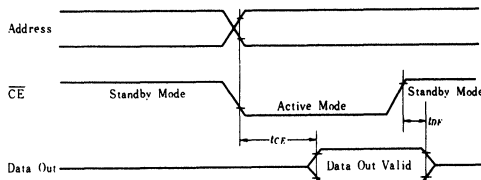
Test Conditions

Input Pulse Levels: 0.8V to 2.2V
 Input Rise and Fall Times: $\leq 20\text{ ns}$
 Output Load: 1TTL Gate + 100 pF
 Reference Level for Measuring Timing: Inputs 1V and 2V
 Outputs 0.8V and 2V

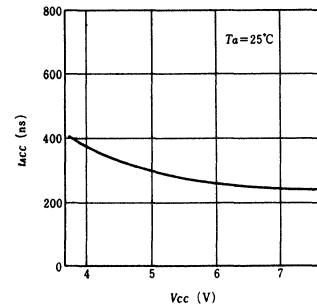
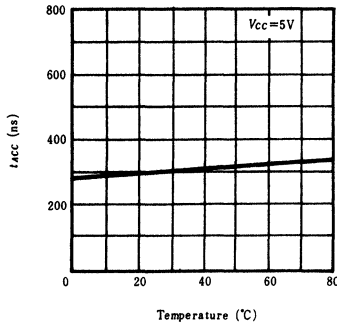
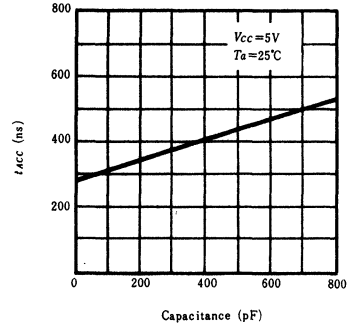
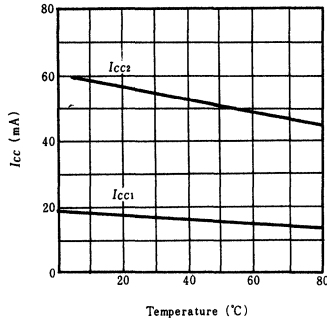
READ MODE ($\overline{\text{CE}}=V_{IL}$)



STANDBY MODE ($\overline{\text{OE}}=V_{IL}$)



TYPICAL CHARACTERISTICS



DC PROGRAMMING CHARACTERISTICS (Ta=25°C±5°C, VCC=5V±5%, VPP=25V±1V)

Parameter	Symbol	Test Condition	min.	typ.	max.	Unit
Input Leakage Current	I_{LI}	$V_{IH}=5.25V$	—	—	10	μA
V_{PP} Supply Current	I_{PP1}	$\overline{CE}=V_{IL}$	—	—	5	mA
V_{PP} Supply Current During Programming	I_{PP2}	$\overline{CE}=V_{IH}$	—	—	30	mA
V_{CC} Supply Current	I_{CC}		—	—	100	mA
Input Low Level	V_{IL}		-0.1	—	0.8	V
Input High Level	V_{IH}		2.0	—	$V_{CC}+1$	V

AC PROGRAMMING CHARACTERISTICS (Ta=25°C±5°C, VCC=5V±5%, VPP=25V±1V)

Parameter	Symbol	Test Condition	min.	typ.	max.	Unit
Address Setup Time	t_{AS}		2	—	—	μs
OE Setup Time	t_{OES}		2	—	—	μs
Data Setup Time	t_{DS}		2	—	—	μs
Address Hold Time	t_{AH}		2	—	—	μs
OE Hold Time	t_{OEH}		5	—	—	μs
Data Hold Time	t_{DH}		2	—	—	μs
OE to Output Float Delay*	t_{DF}	$\overline{CE}=V_{IL}$	0	—	120	ns
OE to Output Delay	t_{OE}	$\overline{CE}=V_{IL}$	—	—	120	ns
Program Pulse Width	t_{PW}		45	50	55	ms
Program Pulse Rise Time	t_{PRT}		5	—	—	ns
Program Pulse Fall Time	t_{PFT}		5	—	—	ns

Notes: V_{CC} must be applied simultaneously or before V_{PP} and removed simultaneously or after V_{PP} .

*: t_{DF} defines the time at which the output achieves the open circuit condition and is not referenced to output voltage levels.

